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SPECIFICATION

COSTONI			
MODULE	NO.:	WH1602A-NO	GG-CT
APPROV			
SALES BY	APPROVED BY	CHECKED BY	PREPARED BY
ISSUED DATE:			

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1. Module Classification Information

 $\begin{array}{ccccc} \underline{\mathbf{W}} \, \underline{\mathbf{H}} & \underline{\mathbf{1}} \, \underline{\mathbf{6}} \, \underline{\mathbf{0}} \, \underline{\mathbf{2}} & \underline{\mathbf{A}} - \underline{\mathbf{N}} \, \underline{\mathbf{G}} \, \underline{\mathbf{G}} - & \underline{\mathbf{CT}} \\ \underline{\mathbf{0}} \, \underline{\mathbf{0}} & \underline{\mathbf{3}} & \underline{\mathbf{4}} & \underline{\mathbf{5}} \, \underline{\mathbf{6}} \, \underline{\mathbf{7}} & \underline{\mathbf{8}} \end{array}$

① Brand: WINSTAR DISPLAY CORPORATION

② Display Type: H→Character Type, G→Graphic Type

3 Display Font: Character 16 words, 2Lines.

Model serials no.

direction

⑤ Backlight Type : N→Without backlight

 $B \rightarrow EL$, Blue green $A \rightarrow LED$, Amber $D \rightarrow EL$, Green $R \rightarrow LED$, Red $W \rightarrow EL$, White $O \rightarrow LED$, Orange $F \rightarrow CCFL$, White $G \rightarrow LED$, Green

Y→LED, Yellow Green

© LCD Mode : $B \rightarrow TN$ Positive, Gray $T \rightarrow FSTN$ Negative

N→TN Negative, G→STN Positive, Gray

Y→STN Positive, Yellow Green

M→STN Negative, Blue

F→FSTN Positive

② LCD Polarize A→Reflective, N.T, 6:00 H→Transflective, W.T,6:00

Type/ Temperature D→Reflective, N.T, 12:00 K→Transflective, W.T,12:00 range/ View G→Reflective, W. T, 6:00 C→Transmissive, N.T,6:00

J→Reflective, W. T, 12:00 F→Transmissive, N.T,12:00

B→Transflective, N.T,6:00 I→Transmissive, W. T, 6:00

E→Transflective, N.T.12:00 L→Transmissive, W.T,12:00

Special Code
CT : English and Cyrillic Standard font

2.Precautions in use of LCD Modules

- (1)Avoid applying excessive shocks to the module or making any alterations or modifications to it.
- (2)Don't make extra holes on the printed circuit board, modify its shape or change the components of LCD module.
- (3)Don't disassemble the LCM.
- (4)Don't operate it above the absolute maximum rating.
- (5)Don't drop, bend or twist LCM.
- (6)Soldering: only to the I/O terminals.
- (7)Storage: please storage in anti-static electricity container and clean environment.

3. General Specification

Item	Dimension	Unit
Number of Characters	16 characters x 2 Lines	_
Module dimension	84.0 x 44.0 x 9.7(MAX)	mm
View area	66.0 x 16.0	mm
Active area	56.20 x 11.5	mm
Dot size	0.55 x 0.65	mm
Dot pitch	0.60 x 0.70	mm
Character size	2.95 x 5.55	mm
Character pitch	3.55 x 5.95	mm
LCD type	STN, Positive, Reflective, Gray	
Duty	1/16	
View direction	6 o'clock	
Backlight Type	N/A	

4. Absolute Maximum Ratings

Item	Symbol	Min	Тур	Max	Unit
Operating Temperature	T_{OP}	-20	_	+70	$^{\circ}\!\mathbb{C}$
Storage Temperature	T_{ST}	-30	_	+80	$^{\circ}\!\mathbb{C}$
Input Voltage	$V_{\rm I}$	V_{SS}	_	V_{DD}	V
Supply Voltage For Logic	V_{DD} - V_{SS}	-0.3	_	7	V
Supply Voltage For LCD	V_{DD} - V_{0}	-0.3		13	V

5.Electrical Characteristics

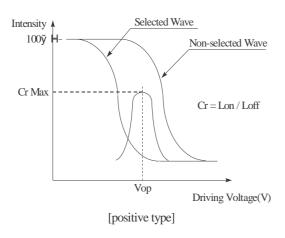
Item	Symbol	Condition	Min	Тур	Max	Unit
Supply Voltage For Logic	V_{DD} - V_{SS}	_	4.5	_	5.5	V
		Ta=-20°C	_	_	5.2	V
Supply Voltage For LCD	V_{DD} - V_0	Ta=25°C	_	3.8	_	V
		Ta=+70°C	3.2	_	_	V
Input High Volt.	V_{IH}	_	2.2	_	V_{DD}	V
Input Low Volt.	$V_{\rm IL}$	_	_	_	0.6	V
Output High Volt.	V_{OH}	_	2.4	_	_	V
Output Low Volt.	V_{OL}	_	_	_	0.4	V
Supply Current	I_{DD}	V _{DD} =5V	_	1.2	_	mA

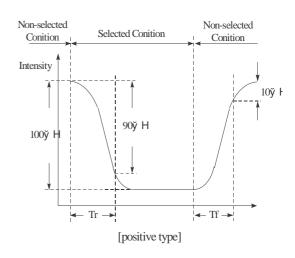
6.Optical Characteristics

Item	Symbol	Condition	Min	Тур	Max	Unit
View Angle	(V) θ	CR≧2	10	_	105	deg
110 11 111910	(Η) φ	CR≧2	-30		30	deg
Contrast Ratio	CR	_	_	3	_	_
Response Time	T rise	_	_	150	200	ms
	T fall	_	_	150	200	ms

Definition of Operation Voltage (Vop)

Definition of Response Time (Tr, Tf)





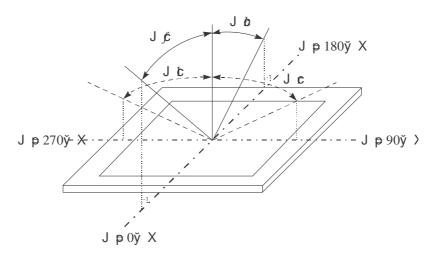
Conditions:

Operating Voltage : Vop

Viewing Angle(θ , ϕ) : 0° , 0°

Frame Frequency : 64 HZ $\;\;$ Driving Waveform : 1/N duty , 1/a bias

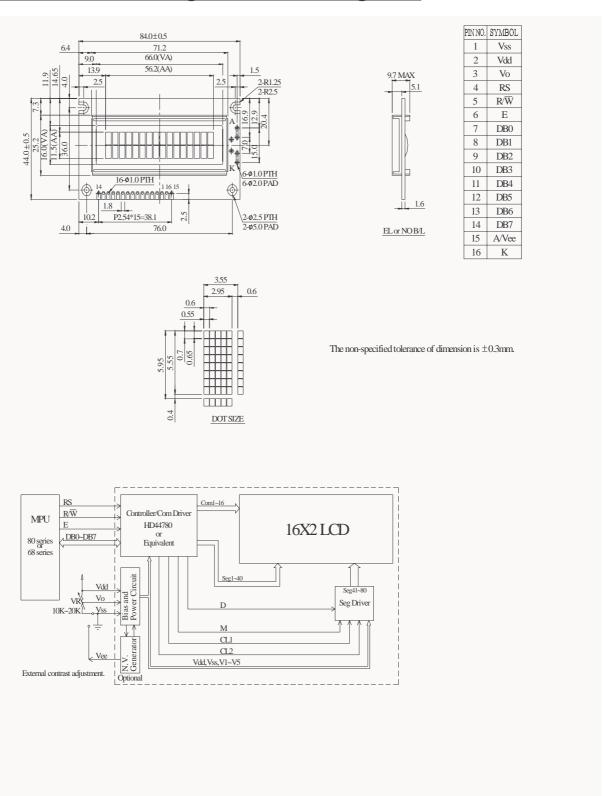
Definition of viewing angle (CR \geq 2)



7.Interface Pin Function

Pin No.	Symbol	Level	Description
1	V_{SS}	0V	Ground
2	V_{DD}	5.0V	Supply Voltage for logic
3	VO	(Variable)	Operating voltage for LCD
4	RS	H/L	H: DATA, L: Instruction code
5	R/W	H/L	H: Read(MPU→Module) L: Write(MPU→Module)
6	Е	H,H→L	Chip enable signal
7	DB0	H/L	Data bit 0
8	DB1	H/L	Data bit 1
9	DB2	H/L	Data bit 2
10	DB3	H/L	Data bit 3
11	DB4	H/L	Data bit 4
12	DB5	H/L	Data bit 5
13	DB6	H/L	Data bit 6
14	DB7	H/L	Data bit 7
15	A	_	NC
16	K	_	NC

8. Contour Drawing & Block Diagram



Character located 1 2 3 4 5 6 7 8 9 10 11 12 13 14 15 16
DDRAM address 00 01 02 03 04 05 06 07 08 09 0A 0B 0C 0D 0E 0F
DDRAM address 40 41 42 43 44 45 46 47 48 49 4A 4B 4C 4D 4E 4F

9. Function Description

The LCD display Module is built in a LSI controller, the controller has two 8-bit registers, an instruction register (IR) and a data register (DR).

The IR stores instruction codes, such as display clear and cursor shift, and address information for display data RAM (DDRAM) and character generator (CGRAM). The IR can only be written from the MPU. The DR temporarily stores data to be written or read from DDRAM or CGRAM. When address information is written into the IR, then data is stored into the DR from DDRAM or CGRAM. By the register selector (RS) signal, these two registers can be selected.

RS	R/W	Operation
0	0	IR write as an internal operation (display clear, etc.)
0	1	Read busy flag (DB7) and address counter (DB0 to DB7)
1	0	Write data to DDRAM or CGRAM (DR to DDRAM or CGRAM)
1	1	Read data from DDRAM or CGRAM (DDRAM or CGRAM to DR)

Busy Flag (BF)

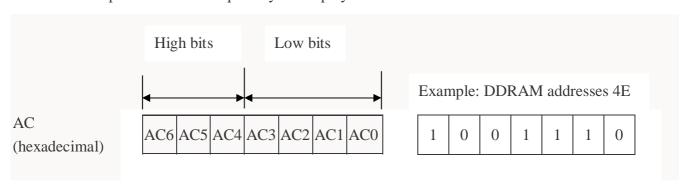
When the busy flag is 1, the controller LSI is in the internal operation mode, and the next instruction will not be accepted. When RS=0 and R/W=1, the busy flag is output to DB7. The next instruction must be written after ensuring that the busy flag is 0.

Address Counter (AC)

The address counter (AC) assigns addresses to both DDRAM and CGRAM

Display Data RAM (DDRAM)

This DDRAM is used to store the display data represented in 8-bit character codes. Its extended capacity is 80×8 bits or 80 characters. Below figure is the relationships between DDRAM addresses and positions on the liquid crystal display.



Display position DDRAM address

1	_	5	7	J	U	,	U		10	11	12	13	17	13	10
00	01	02	03	04	05	06	07	08	09	0A	0B	0C	0D	0E	0F
40	41	42	43	44	45	46	47	48	49	4A	4B	4C	4D	4E	4F

9 10 11 12 13 14 15 16

2-Line by 16-Character Display

Character Generator ROM (CGROM)

The CGROM generate 5×8 dot or 5×10 dot character patterns from 8-bit character codes. See Table 2.

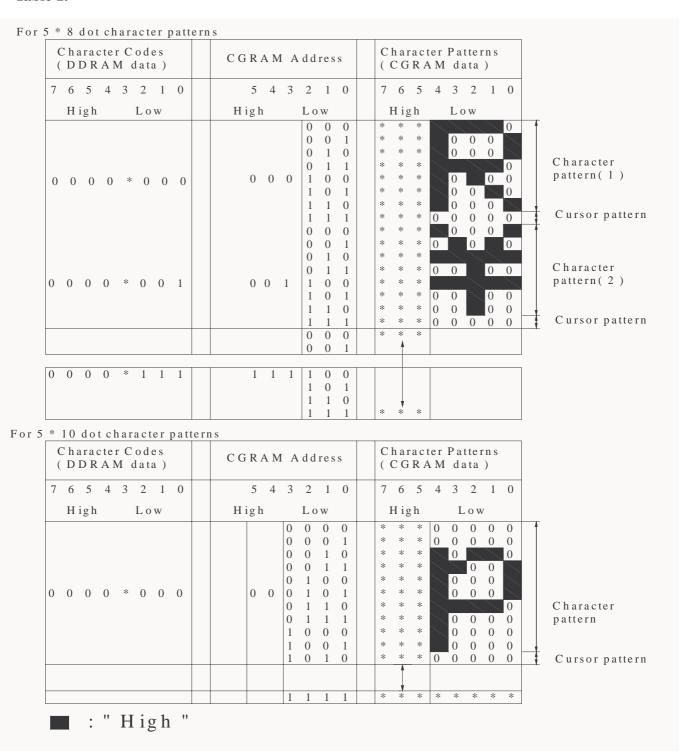
Character Generator RAM (CGRAM)

In CGRAM, the user can rewrite character by program. For 5×8 dots, eight character patterns can be written, and for 5×10 dots, four character patterns can be written.

Write into DDRAM the character code at the addresses shown as the left column of table 1. To show the character patterns stored in CGRAM.

Relationship between CGRAM Addresses, Character Codes (DDRAM) and Character patterns

Table 1.



10.Character Generator ROM Pattern

Table.2

Upper 4 bit Lower	LLLL	LLLH	LLHL	LLHH	LHLL	LHLH	LHHL	LHHH	HLLL	HLLH	HLHL	НГНН	HHLL	HHLH	HHHL	ннн
4 bit	CG RAM (1)						٠.						•	:		-::
LLLH	CG RAM (2)		:				•:::							1		! :
LLHL	CG RAM (3)							! -					1	:::		
LLHH	CG RAM (4)					=	ŧ							::		
LHLL	CG RAM (5)		-4:-					·i					i			
LHLH	CG RAM (6)					!	====									
LHHL	CG RAM (7)		8.			I.,.I		i:						::		
LHHH	CG RAM (8)		:=	:-::				.				:	-:::			
HLLL	CG RAM (1)					:-:	l	:-::					·::-:			
HLLH	CG RAM (2)					1	1	•:			:		:::	-1		
HLHL	CG RAM (3)		:-[-:	::	!		:					: :	:: ::			
НГНН	CG RAM (4)		[::			! -::				•	.::	:: ::		:::	
HHLL	CG RAM (5)		;:	·:.			i.							- -		
ННГН	CG RAM (6)		••••								`i		::			
HHHL	CG RAM (7)		::			"	i-":						.::-	···	-: :-	
нннн	CG RAM (8)			•**			::::							==	::::	

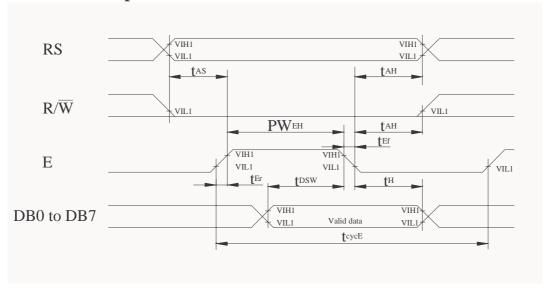
11.Instruction Table

Instruction				Ins	structi	ion Co	ode				Description	Execution time
Thisti detion	RS	R/W	DB7	DB6	DB5	DB4	DB3	DB2	DB1	DB0	Description	(fosc=270Khz)
Clear Display	0	0	0	0	0	0	0	0	0	1	Write "00H" to DDRAM and set DDRAM address to "00H" from AC	1.53ms
Return Home	0	0	0	0	0	0	0	0	1	_	Set DDRAM address to "00H" from AC and return cursor to its original position if shifted. The contents of DDRAM are not changed.	1.53ms
Entry Mode Set	0	0	0	0	0	0	0	1	I/D	SH	Assign cursor moving direction and enable the shift of entire display.	39 μ s
Display ON/OFF Control	0	0	0	0	0	0	1	D	С	В	Set display (D), cursor (C), and blinking of cursor (B) on/off control bit.	39 μ s
Cursor or Display Shift	0	0	0	0	0	1	S/C	R/L	_	_	Set cursor moving and display shift control bit, and the direction, without changing of DDRAM data.	39 μ s
Function Set	0	0	0	0	1	DL	N	F	_	_	Set interface data length (DL:8-bit/4-bit), numbers of display line (N:2-line/1-line)and, display font type (F:5×11 dots/5×8 dots)	39 μ s
Set CGRAM Address	0	0	0	1	AC5	AC4	AC3	AC2	AC1	AC0	Set CGRAM address in address counter.	39 μ s
Set DDRAM Address	0	0	1	AC6	AC5	AC4	AC3	AC2	AC1	AC0	Set DDRAM address in address counter.	39 μ s
Read Busy Flag and Address	0	1	BF	AC6	AC5	AC4	AC3	AC2	AC1	AC0	Whether during internal operation or not can be known by reading BF. The contents of address counter can also be read.	0 μ s
Write Data to RAM	1	0	D7	D6	D5	D4	D3	D2	D1	D0	Write data into internal RAM (DDRAM/CGRAM).	43 μ s
Read Data from RAM	1	1	D7	D6	D5	D4	D3	D2	D1	D0	Read data from internal RAM (DDRAM/CGRAM).	43 μ s

* "-": don't care

12. Timing Characteristics

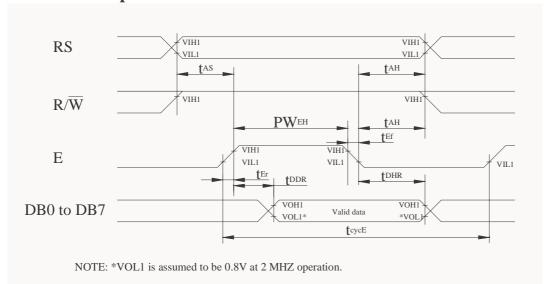
12.1 Write Operation



Ta= 25° C, VDD= 5.0 ± 0.5 V

Item	Symbol	Min	Тур	Max	Unit
Enable cycle time	$t_{ m cycE}$	1200	_	_	ns
Enable pulse width (high level)	PW_{EH}	140	_	_	ns
Enable rise/fall time	$t_{\rm Er}, t_{\rm Ef}$	_	_	25	ns
Address set-up time (RS, R/W to E)	t_{AS}	0	_	_	ns
Address hold time	t_{AH}	10	_	_	ns
Data set-up time	$t_{ m DSW}$	40	_	_	ns
Data hold time	$t_{\rm H}$	10	_	_	ns

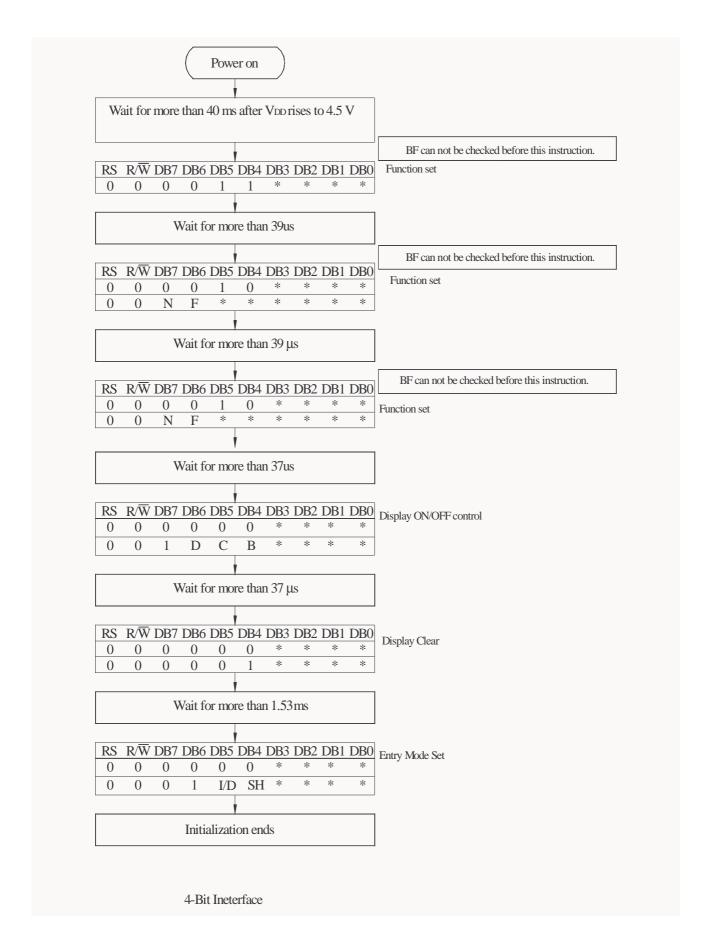
12.2 Read Operation

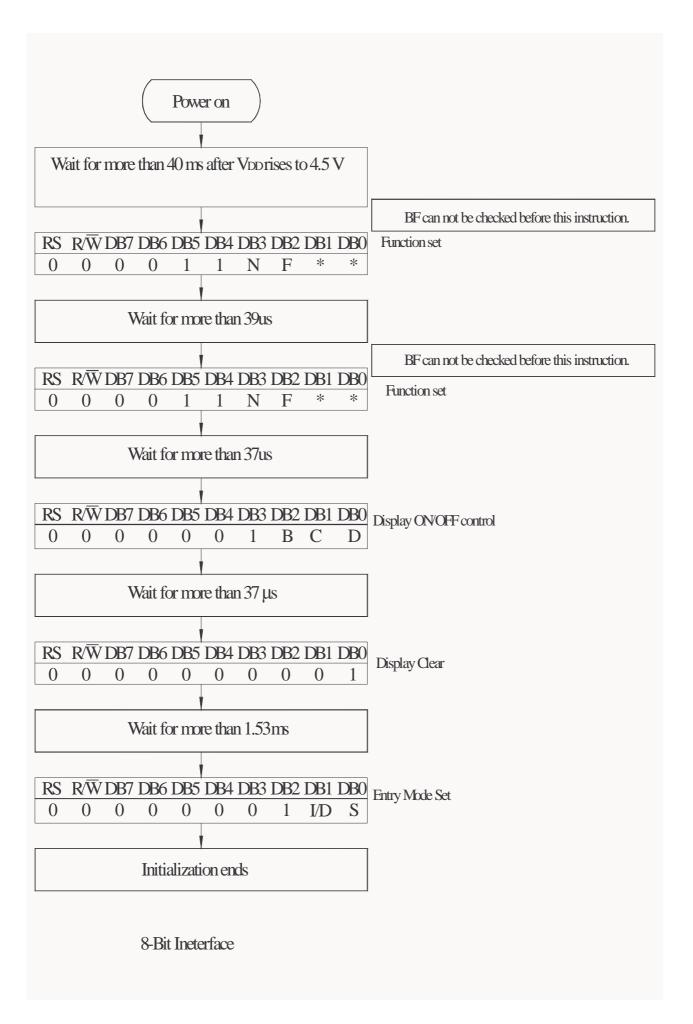


Ta=25°C, VDD=5. 0 ± 0.5 V

Item	Symbol	Min	Тур	Max	Unit
Enable cycle time	$t_{\rm cycE}$	1200	_	_	ns
Enable pulse width (high level)	PW_{EH}	140	_	_	ns
Enable rise/fall time	$t_{\rm Er}, t_{\rm Ef}$	_	_	25	ns
Address set-up time (RS, R/W to E)	t _{AS}	0	_	_	ns
Address hold time	t_{AH}	10	_	_	ns
Data delay time	t _{DDR}	_	_	100	ns
Data hold time	t _{DHR}	10	_	_	ns

13.Initializing of LCM





14. Quality Assurance

Screen Cosmetic Criteria

Item	Defect	Judgment Criterion	Partition
1	Spots	A)Clear Size: d mm Acceptable Qty in active area $d \le 0.1$ Disregard $0.1 < d \le 0.2$ $d \le 0.3$ $d \le 0.3$ Once: Including pin holes and defective dots which must be within one pixel size. B)Unclear Size: d mm Acceptable Qty in active area $d \le 0.2$ Disregard $d \le 0.2$ Disregard $d \le 0.2 < d \le 0.5$ $d \le 0.5 < d \le 0.7$	Minor
2	Bubbles in Polarize	Size: d mm Acceptable Qty in active area $d \le 0.3$ Disregard $0.3 < d \le 1.0$ 3 $1.0 < d \le 1.5$ 1 $1.5 < d$ 0	Minor
3	Scratch	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	
4	Allowable Density	-	Minor
5	Coloration	Not to be noticeable coloration in the viewing area of the LCD panels. Back-light type should be judged with back-light on state only.	Minor

15.Reliability

Content of Reliability Test

Environmental Test					
Test Item	Content of Test	Test Condition	Applicable Standard		
High Temperature storage	Endurance test applying the high storage temperature for a long time.	80°C 200hrs			
Low Temperature storage	Endurance test applying the high storage temperature for a long time.	-30℃ 200hrs			
High Temperature Operation	Endurance test applying the electric stress (Voltage & Current) and the thermal stress to the element for a long time.	70°C 200hrs			
Low Temperature Operation	Endurance test applying the electric stress under low temperature for a long time.	-20°C 200hrs			
High Temperature/ Humidity Storage	Endurance test applying the high temperature and high humidity storage for a long time.	80°C,90%RH 96hrs			
High Temperature/ Humidity Operation	Endurance test applying the electric stress (Voltage & Current) and temperature / humidity stress to the element for a long time.	70°C,90%RH 96hrs			
Temperature Cycle	Endurance test applying the low and high temperature cycle. -30°C 25°C 80°C 30min 5min 30min 1 cycle	-30°C/80°C 10 cycles			
	Mechanical Tes	t			
Vibration test	Endurance test applying the vibration during transportation and using.	10~22Hz→1.5mmp-p 22~500Hz→1.5G Total 0.5hrs			
Shock test	Constructional and mechanical endurance test applying the shock during transportation.	50G Half sign wave 11 msedc 3 times of each direction			
Atmospheric pressure test	Endurance test applying the atmospheric pressure during transportation by air.	115mbar 40hrs			
	Others				
Static electricity test	Endurance test applying the electric stress to the terminal.	VS=800V,RS=1.5kΩ CS=100pF 1 time			

^{***}Supply voltage for logic system=5V. Supply voltage for LCD system =Operating voltage at 25° C